## **Miniature Surface Mount** LED—OPR5200

## Phototransistor-OPR5500

#### Features:

- Stackable on 2 mm centers
- Vertical or horizontal mounting
- Automatic pick-and-place compatible
- Combine OPR5200 and OPR5500 to create miniature switch

#### Description:

The OPR5200 is a miniature high efficiency GaAIAs light emitting diode in a high temperature polyamide chip carrier that is well suited to space-limited applications which require close channel spacing.

The **OPR5500** is a miniature NPN silicon phototransistor housed in a high temperature polyamide chip carrier that is well suited to space-limited applications which require close channel spacing.

When combing the OPR5200 and OPR5500 (miniature phototransistor), this lateral mounting option can be used to create a non-focused reflective or slotted switch configuration.

These parts can be automatically placed with standard SMD equipment and can be reflow soldered by virtually any conventional means. Wraparound contacts allow it to be mounted face up or on edge for a beam direction parallel to the seating plane.

Output Power

(µW) Min

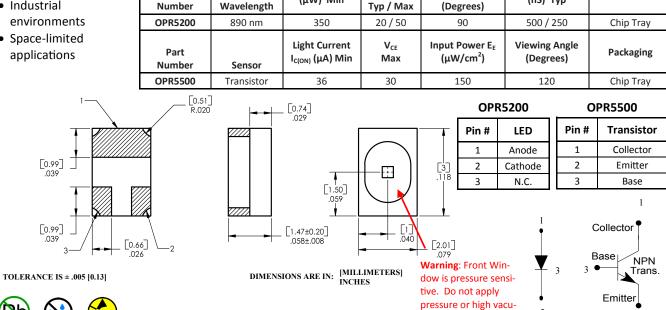
See Application Bulletin 237 for handling instructions

Part

LED Peak

#### Applications:

- Slotted switches
- Industrial environments
- Space-limited applications



**Ordering Information** 

I<sub>⊧</sub> (mA)

**Total Beam** 

Angle

um to window.

Rise / Fall Times

(nS) Typ

Packaging



General Note

TT Electronics reserves the right to make changes in product specification without notice or liability. All information is subject to TT Electronics' own data and is considered accurate at time of going to print.

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**Electronics** 

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# **Miniature Surface Mount**

### LED—OPR5200



### Phototransistor-OPR5500

<b>OPR5200 Absolute Maximum Ratings</b> (T <sub>A</sub> = 25° C unless otherwise noted)			
Storage and Operating Temperature	-55° C to +125° C		
Continuous Forward Current	50 mA		
Peak Forward Current (1 μs pulse width, 10% duty cycle)	1.0 A		
Power Dissipation <sup>(1)</sup>	100 mW		
Solder reflow time within 5°C of peak temperature is 20 to 40 seconds <sup>(2)</sup>	250° C		

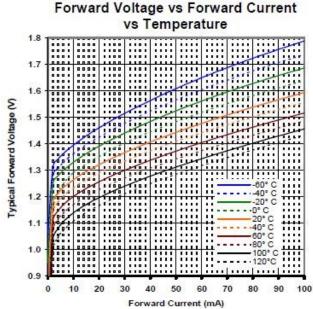
#### **OPR5200 Electrical Characteristics** (T<sub>A</sub> = 25° C unless otherwise noted)

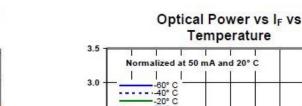
01110200						
SYMBOL	PARAMETER	MIN	ТҮР	МАХ	UNITS	TEST CONDITIONS
Po	Output Power	350	-	-	μW	I <sub>F</sub> = 20 mA
V <sub>F</sub>	Forward Voltage	-	-	1.8	V	I <sub>F</sub> = 20 mA
I <sub>R</sub>	Reverse Current	-	-	100	μA	$V_R = 2 V$
$\lambda_{\mathrm{P}}$	Peak Wavelength	-	890	-	nm	I <sub>F</sub> = 20 mA
$\lambda_{\rm BW}$	Spectral Bandwidth	-	80	-	nm	I <sub>F</sub> = 20 mA
$\theta_{\rm HP}$	Emission Angle	-	±45°	-	-	at half power points
t <sub>r</sub>	Output Rise Time	-	500	-	ns	I <sub>P</sub> = 100 mA, PW = 10.0 μs, D.C. = 10%
t <sub>f</sub>	Output Fall Time	-	250	-	ns	$1p - 100 \text{ mA}, PW - 10.0 \ \mu\text{s}, D.C. = 10\%$

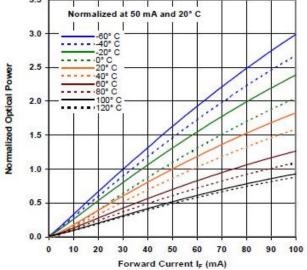
Notes:

(1) Derate at 1.00 mW/° C above 25° C.

(2) Solder time less than 5 seconds at temperature extreme.







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## **Miniature Surface Mount**

### LED—OPR5200



### Phototransistor-OPR5500

<b>OPR5500 Absolute Maximum Ratings</b> (T <sub>A</sub> = 25° C unless otherwise noted)			
Storage and Operating Temperature	-55° C to +125° C		
Collector-Emitter Voltage	30 V		
Emitter-Collector Voltage	5 V		
Power Dissipation <sup>(1)</sup>	100 mW		
Solder reflow time within 5°C of peak temperature is 20 to 40 seconds <sup>(2)</sup>	250° C		

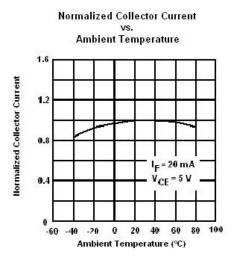
### Electrical Characteristics (T<sub>A</sub> = 25° C unless otherwise noted)

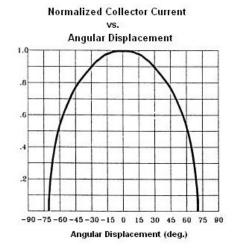
SYMBOL	PARAMETER	MIN	ТҮР	MAX	UNITS	TEST CONDITIONS
I <sub>C(ON)</sub>	On-State Collector Current	36	-	-	μΑ	$V_{CE} = 5 V, E_e = 150 \mu W/cm^2$ (890 nm light source)
I <sub>CEO</sub>	Dark Current	-	-	100	nA	$V_{CE} = 5 V, E_e = 0$
V <sub>(BR)CEO</sub>	Collector-Emitter Breakdown Voltage	30	-	-	V	I <sub>c</sub> = 100 μA
V <sub>(BR)ECO</sub>	Emitter-CollectorBreakdown Voltage	5	-	-	V	I <sub>E</sub> = 100 μA
V <sub>(SAT)</sub>	Saturation Voltage	-	-	0.4	V	$I_{c} = 100 \ \mu A, E_{e} = 5 \ mW/cm^{2}$
t <sub>r,</sub> t <sub>f</sub>	Output Rise and Fall Time	-	2.5	-	μs	$V_{CC}$ = 5 V, $I_{C}$ = 800 $\mu A,~R_{L}$ = 100 $\Omega$

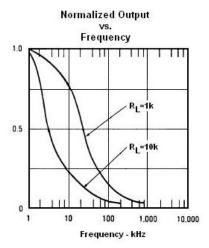
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